

FIG.1

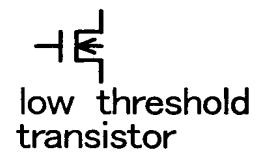
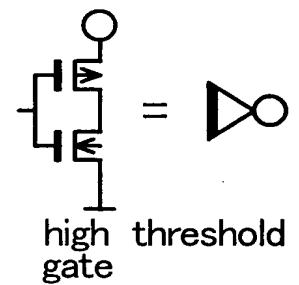
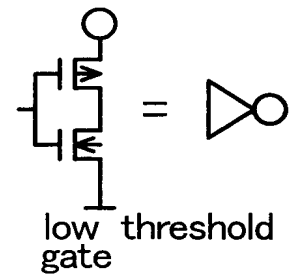
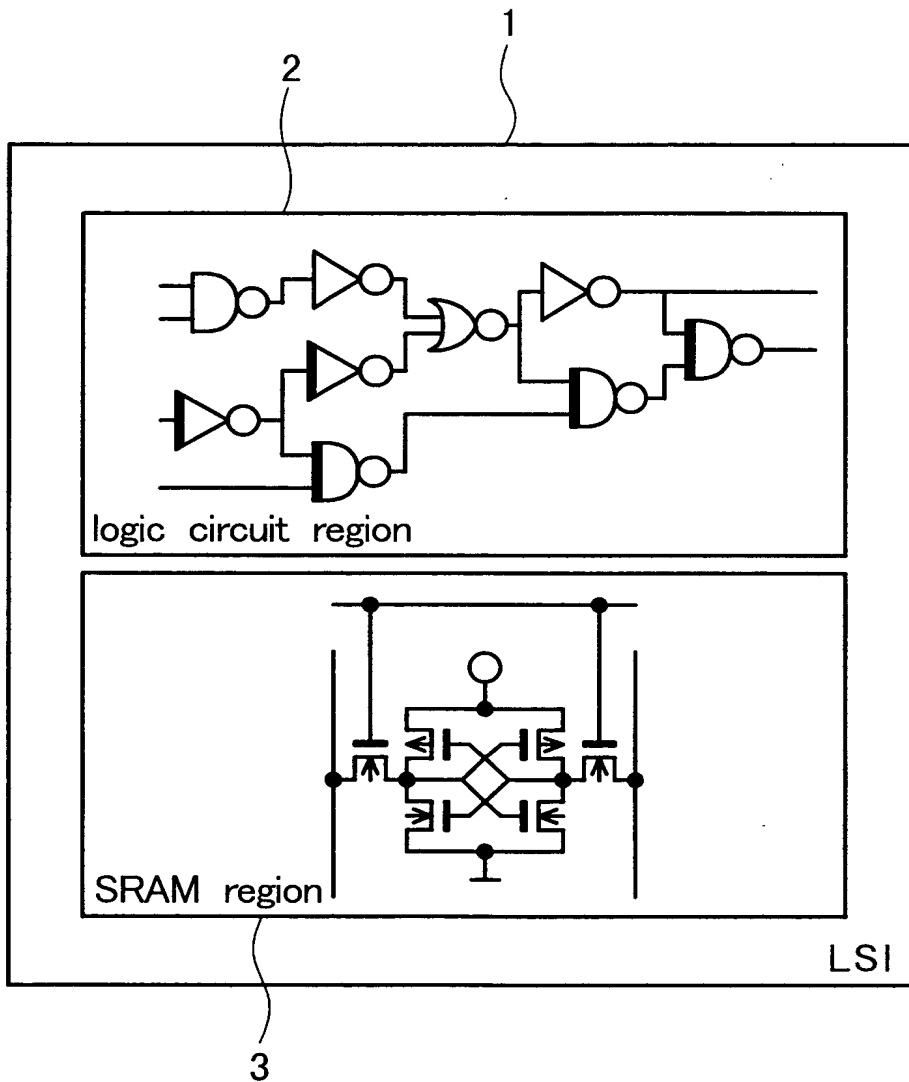


FIG.2

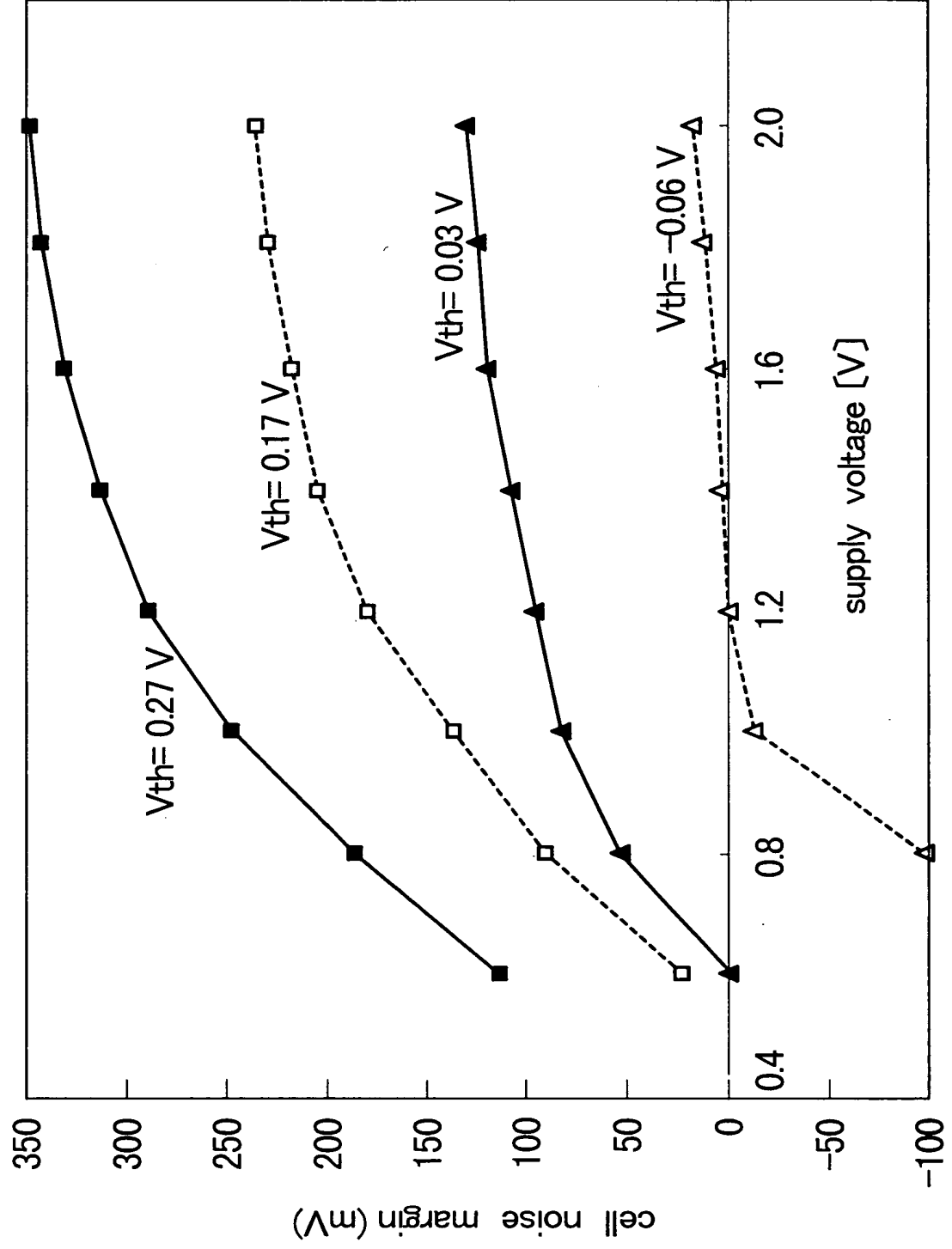


FIG.3

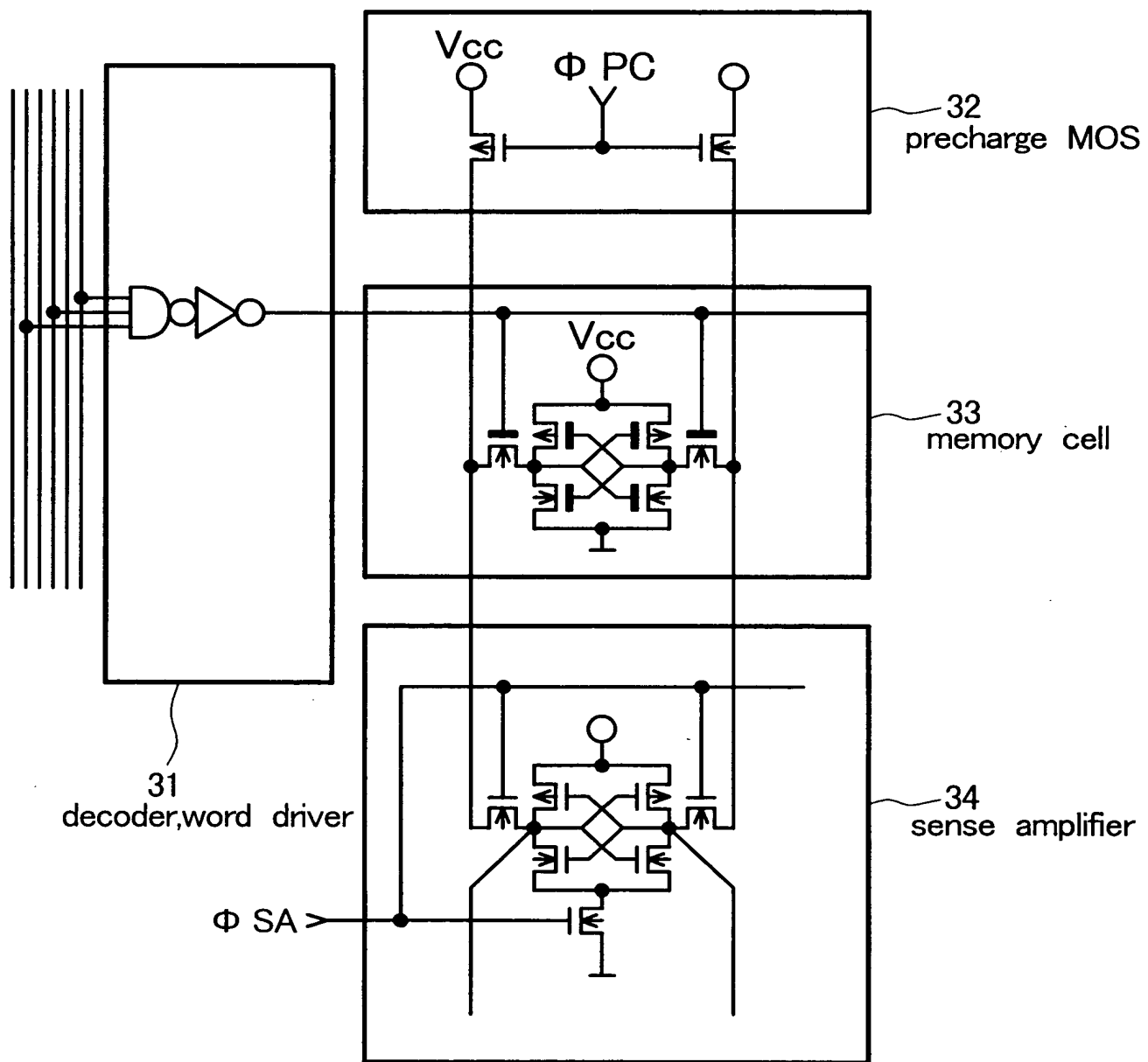


FIG.4A

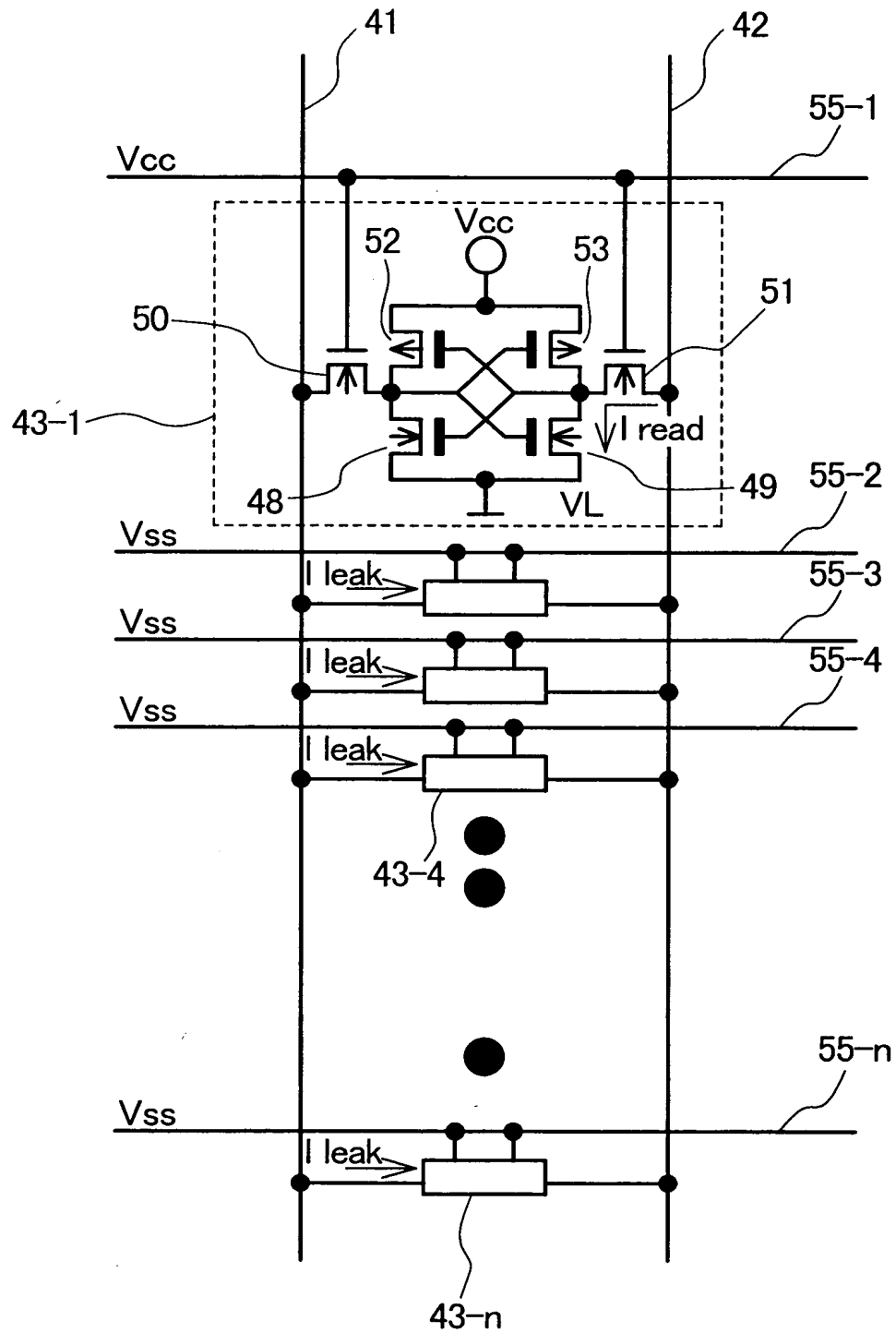


FIG.4B

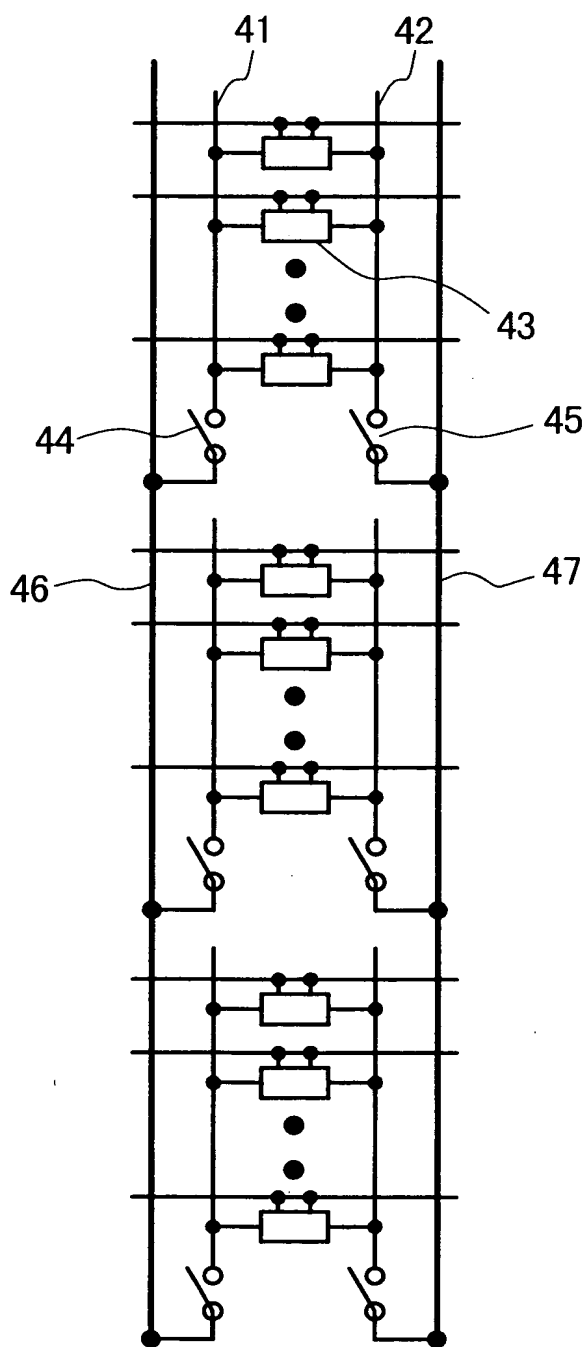


FIG.4C

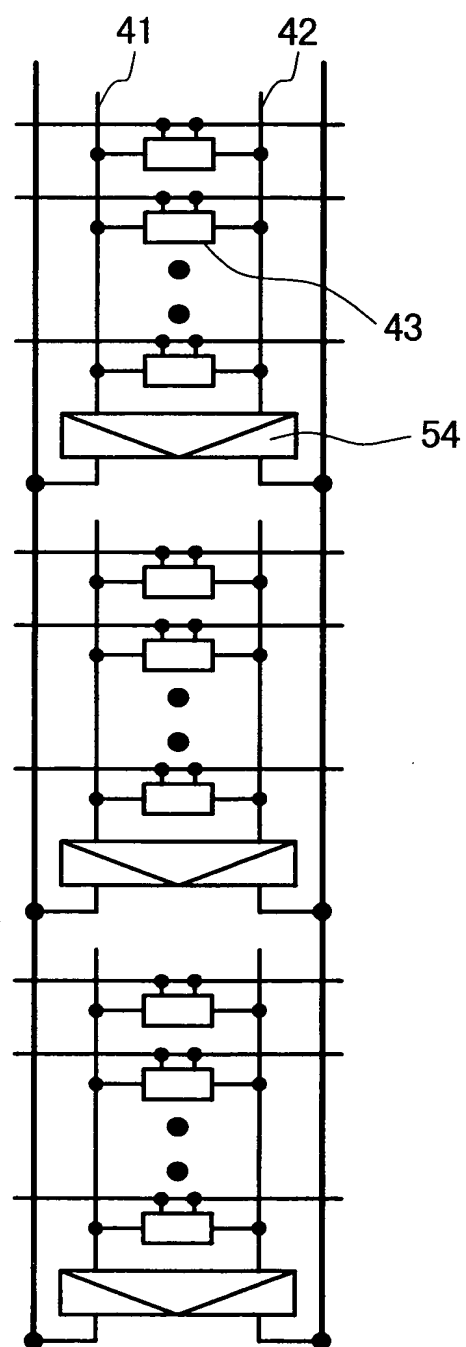


FIG.5

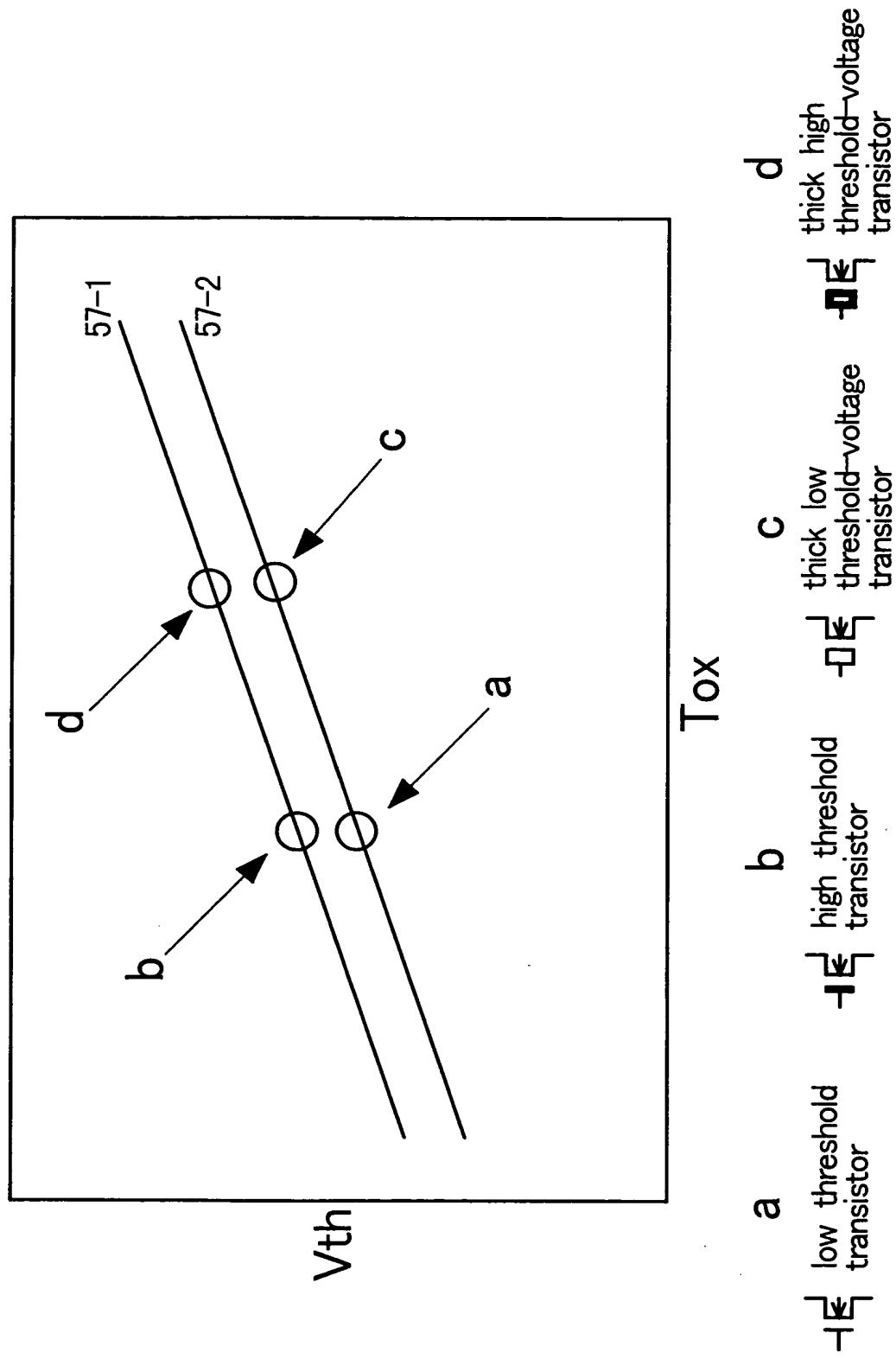


FIG.6

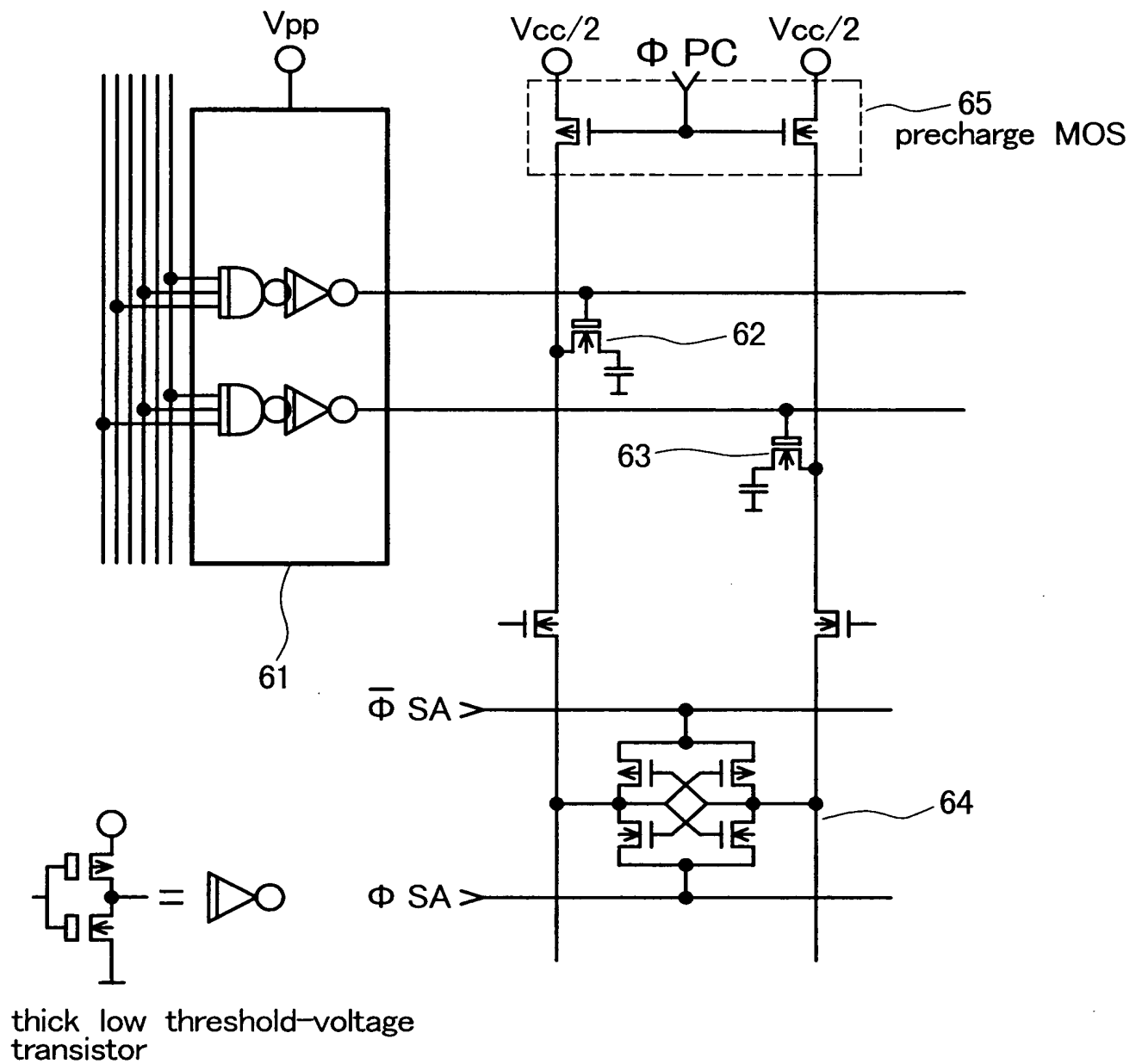


FIG.7

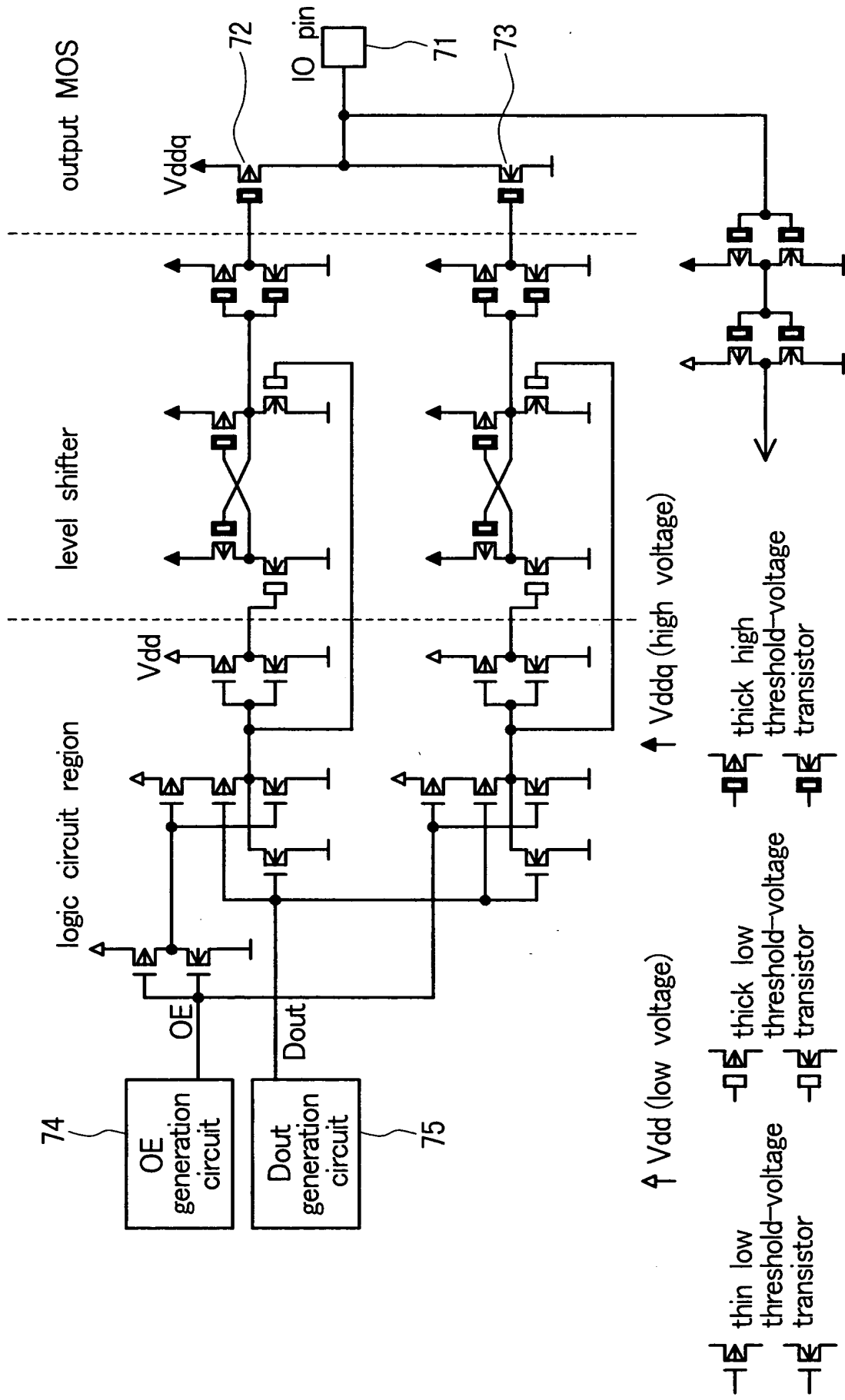
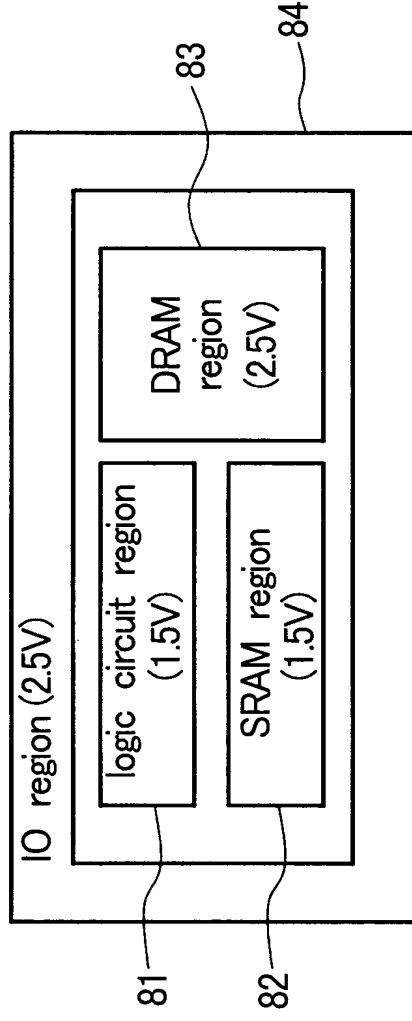


FIG.8



	logic circuit		SRAM		DRAM	IO
	about 90%	about 10%	load MOS	transfer MOS	drive MOS	Tr MOS
threshold voltage	high Vth (0.45V)	low Vth (0.35V)	high Vth (-0.45V)	low Vth (0.35V)	high Vth (0.45V)	high Vth (0.65V)
NMOS						
PMOS						
gate oxide	thin gate oxide (3.2nm)			thin gate oxide (3.2nm)	thick gate oxide (6.5nm)	thick gate oxide (6.5nm)
supply voltage	low voltage (1.5V)			low voltage (1.5V)	high voltage (2.5V)	high voltage (2.5V)
circuitry						
value in parentheses is an example						

FIG. 9

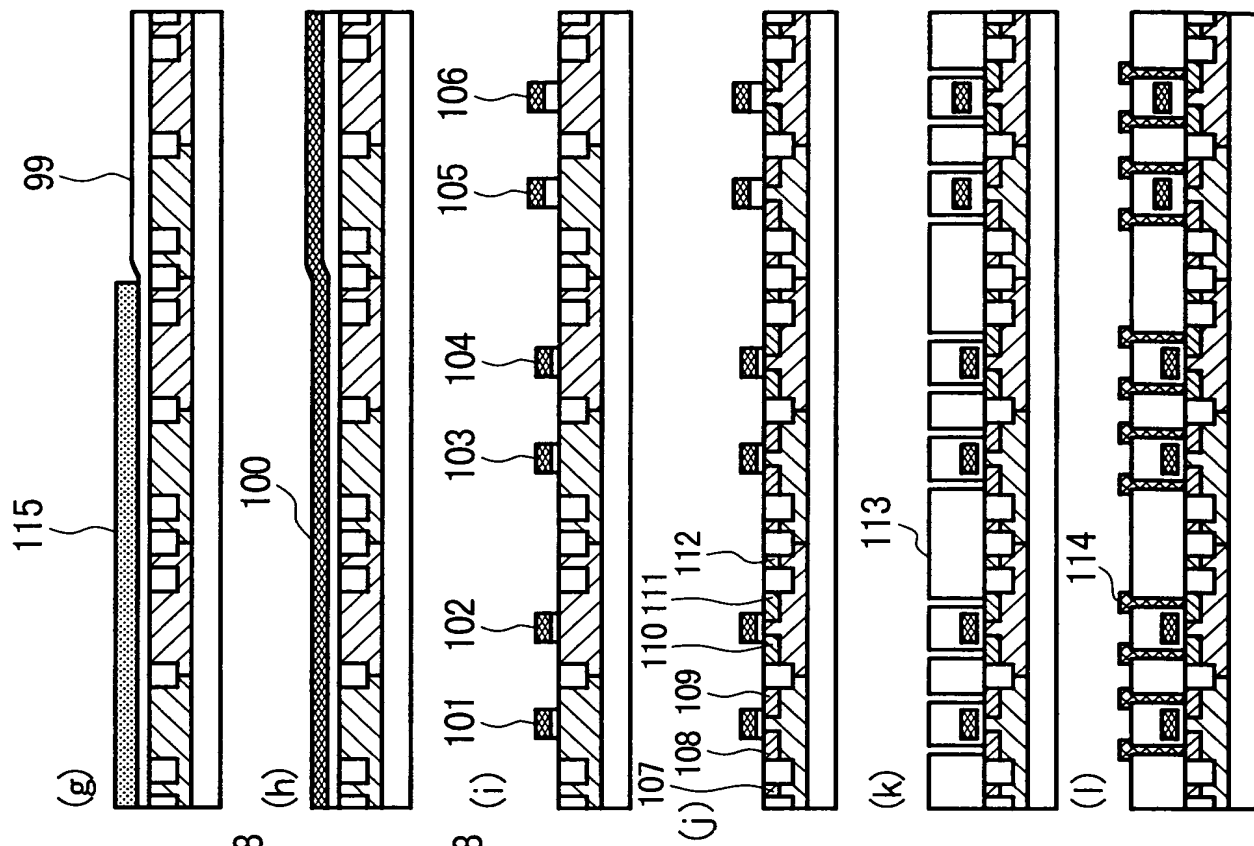
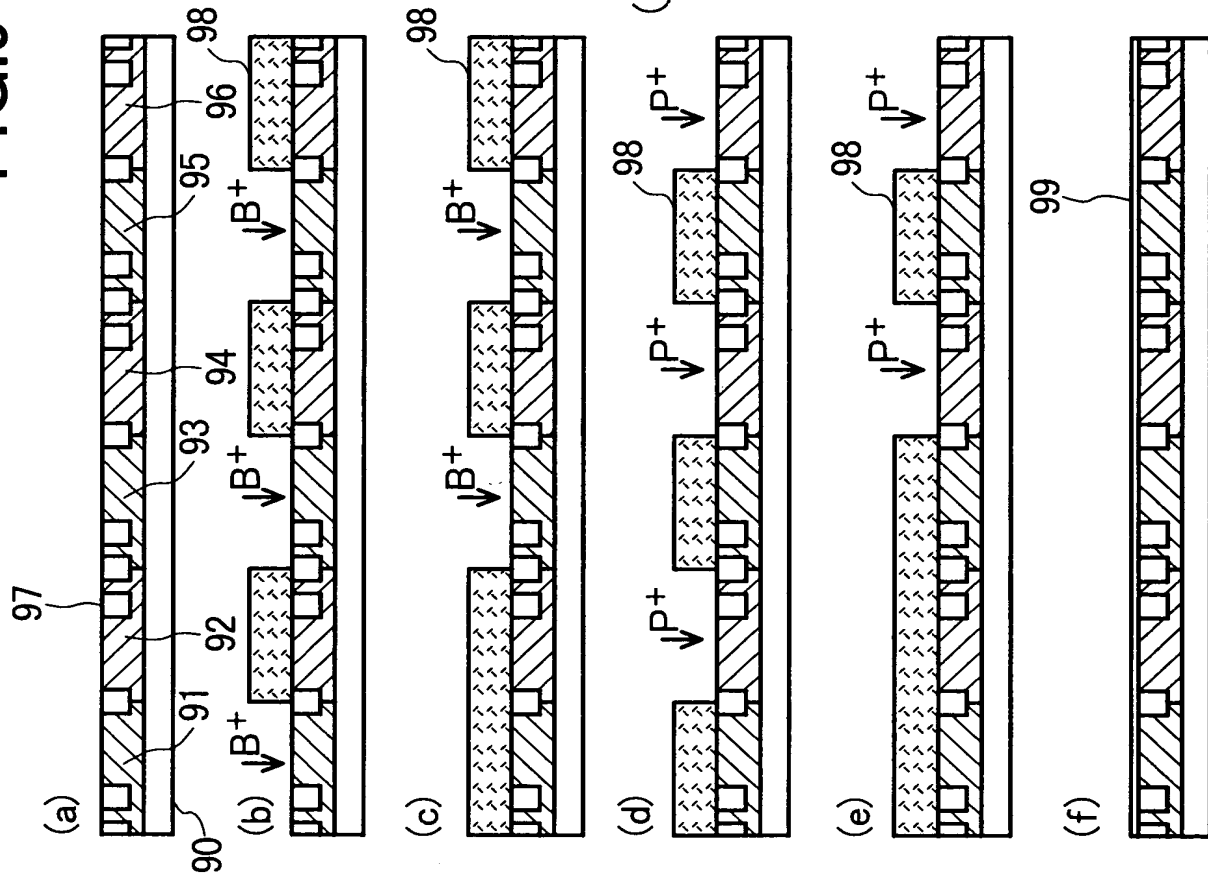


FIG.10

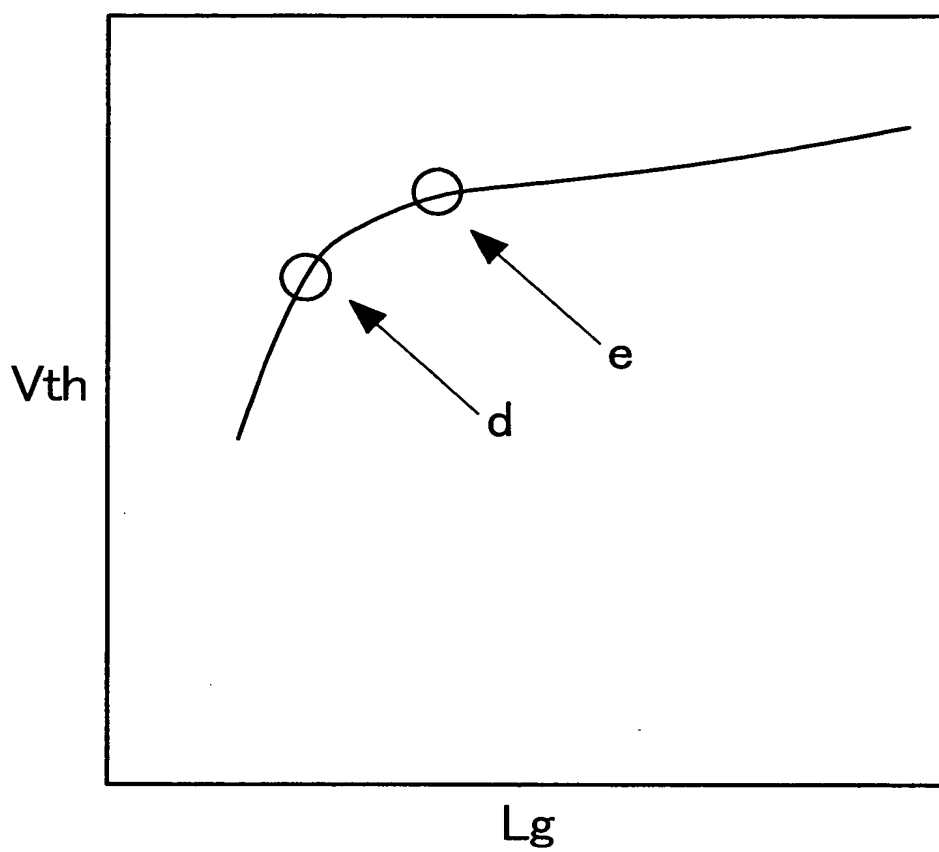


FIG. 11

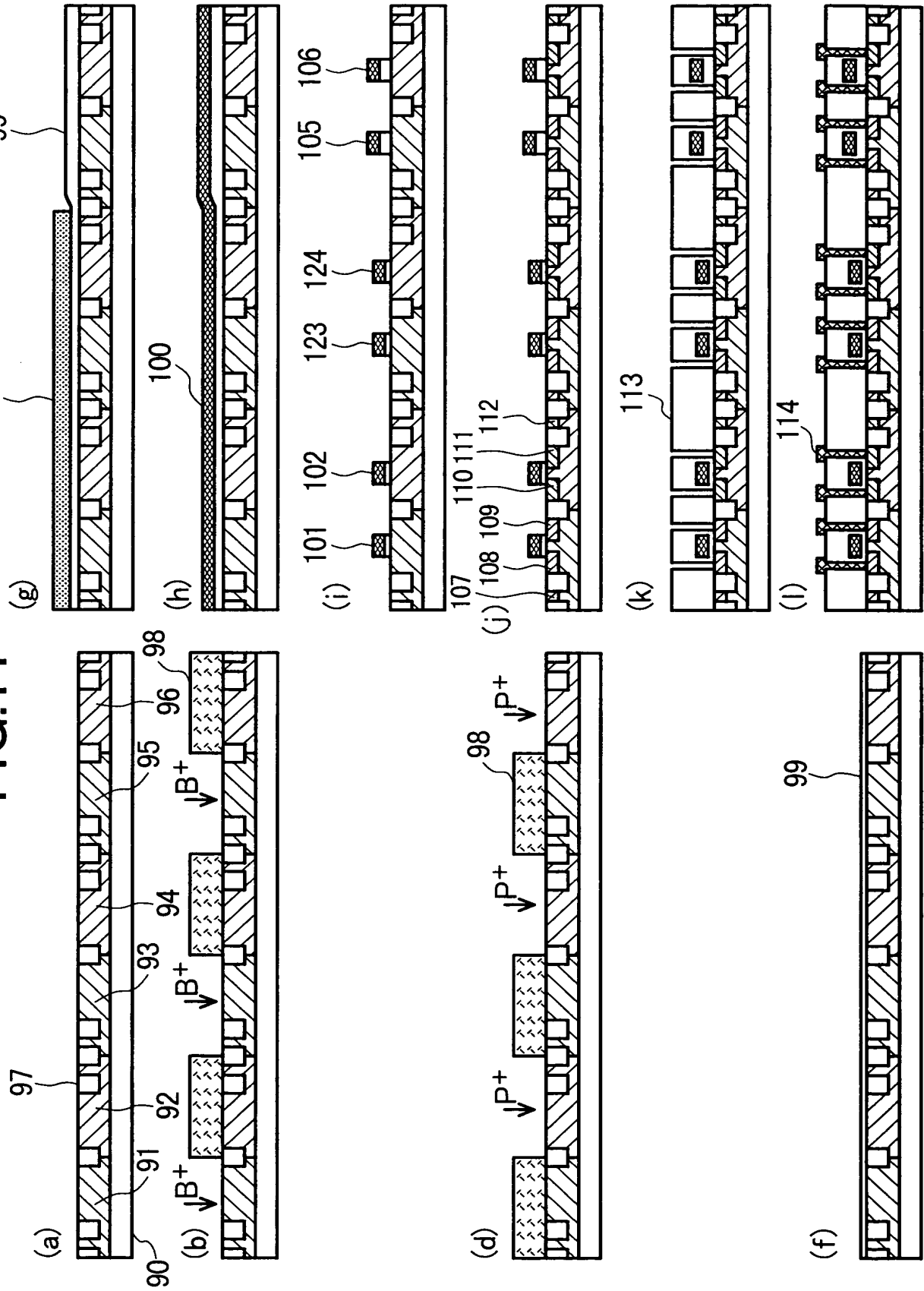


FIG.12

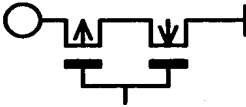
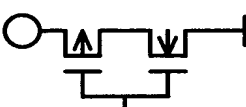
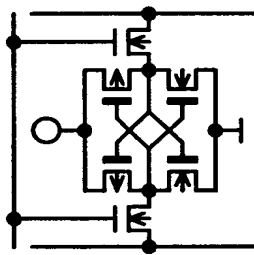
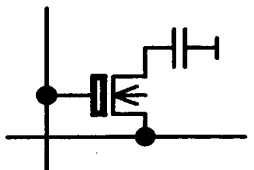
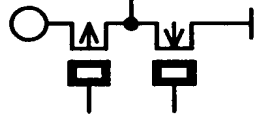



	logic circuit		SRAM			DRAM	IO
	about 90%	about 10%	load MOS	transfer MOS	drive MOS	Tr MOS	
threshold voltage	high Vth (0.45V)	low Vth (0.35V)	high Vth (-0.45V)	low Vth (0.35V)	high Vth (0.45V)	high Vth (0.65V)	high Vth (0.65V)
NMOS	(-0.45V)	(-0.35V)					(-0.65V)
PMOS							
gate oxide	thin gate oxide (3.2nm)	thin gate oxide (3.2nm)		thin gate oxide (3.2nm)		thick gate oxide (6.5nm)	thick gate oxide (6.5nm)
supply voltage	low voltage (1.5V)	low voltage (1.5V)		low voltage (1.5V)		high voltage (2.5V)	high voltage (2.5V)
gate length	long channel (0.18um)	short channel (0.14um)	long channel (0.18um)	short channel (0.14um)	long channel (0.18um)	long channel (0.18um)	long channel (0.14um)
circuitry							
value in parentheses is an example							 thin high threshold-voltage  thin low threshold-voltage  thick high threshold-voltage

FIG.13A

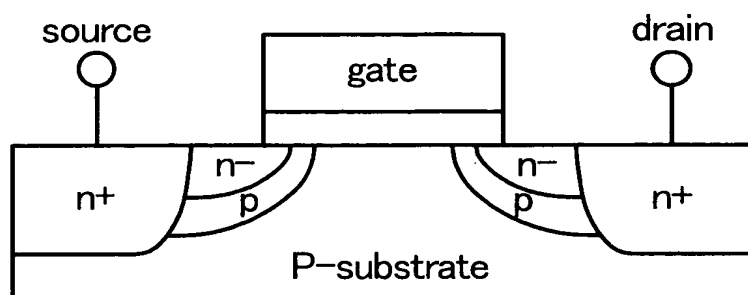


FIG.13B

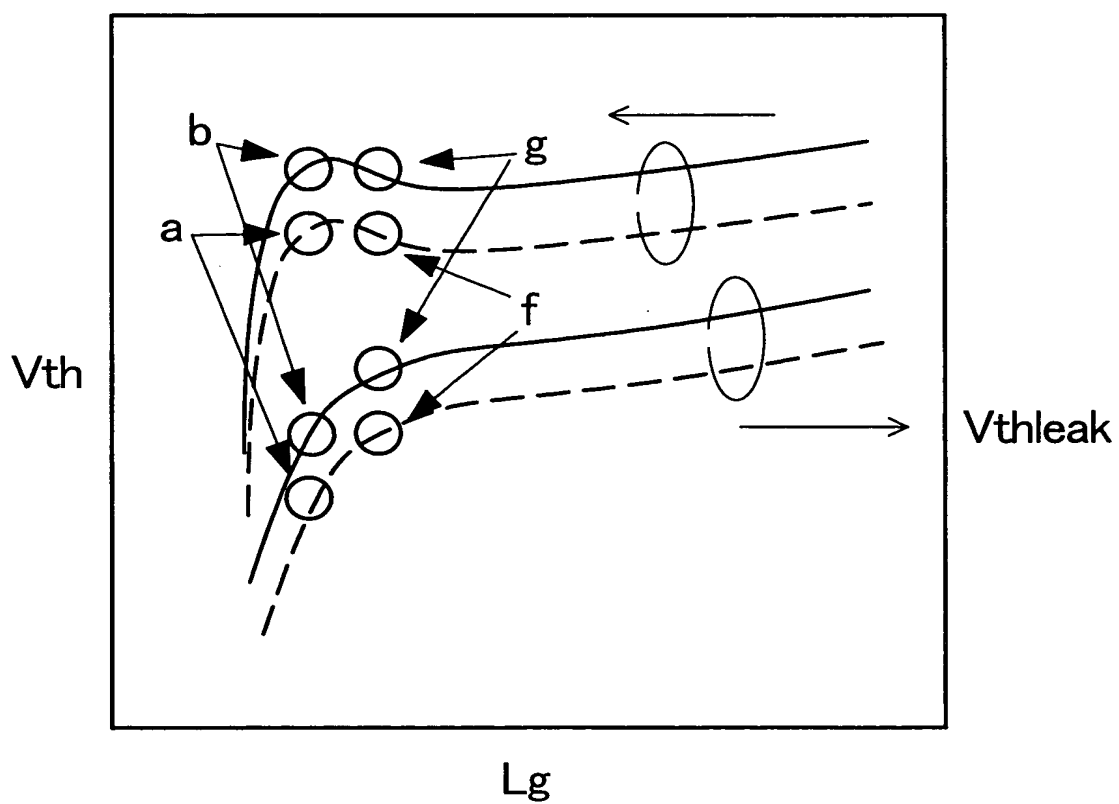


FIG.14

